

Product Summary

| V _{(BR)DSS} | R _{DS(on)TYP} | I _D | |
|----------------------|------------------------|----------------|--|
| 85V | 4.3mΩ@10V | 90A | |



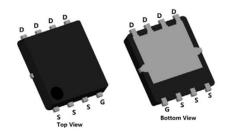
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

Applications

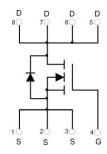
- Power switching application
- DC-DC Converter
- Power Management

Package

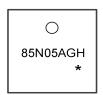


PDFN5X6-8L

Circuit diagram



Marking



85N05AGH :Device Code * :Month Code

Order Information

| Device | Package | Unit/Tape | |
|--------------|------------|-----------|--|
| SP85N05AGHNK | PDFN5X6-8L | 5000 | |



Absolute maximum ratings (Ta=25°C unless otherwise noted)

| Parameter | Symbol | Rating | Unit |
|--|------------------|------------|------------|
| Drain-Source Voltage | V _{DS} | 85 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Continuous Drain Current (Tc=25°C) | I _D | 90 | Α |
| Continuous Drain Current (Tc=100°C) | I _D | 60 | Α |
| Pulsed Drain Current | I _{DM} | 360 | Α |
| Single Pulse Avalanche Energy ¹ | Eas | 784 | mJ |
| Power Dissipation (Tc=25°C) | P _D | 125 | W |
| Thermal Resistance Junction-to-Case | R _{θJC} | 1 | °C/W |
| Storage Temperature Range | T _{STG} | -55 to 150 | $^{\circ}$ |
| Operating Junction Temperature Range | TJ | -55 to 150 | $^{\circ}$ |

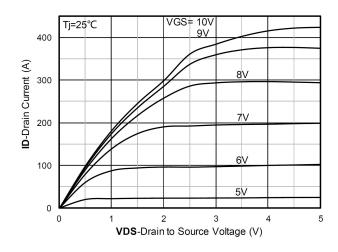
Electrical characteristics (Ta=25°C, unless otherwise noted)

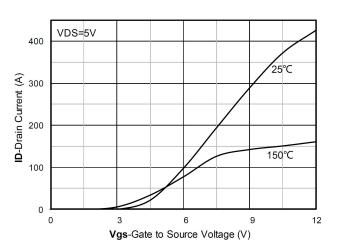
| Characteristics | Symbol | Test Condition | Min | Тур | Max | Unit | |
|---|---------------------|--|-----|------|------|------|--|
| Static Characteristics | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | ID = 250µA, VGS = 0V | 85 | 90 | - | V | |
| Drain Cut-Off Current | I _{DSS} | VDS = 68V, VGS = 0V | - | - | 1 | | |
| Gate Leakage Current | I _{GSS} | VGS = ±20V, VDS = 0V | - | - | ±0.1 | μA | |
| Gate Threshold Voltage | $V_{GS(th)}$ | VDS = VGS, ID = 250μA | 2 | 3 | 4 | V | |
| Drain-Source ON Resistance | R _{DS(ON)} | VGS = 10V, ID = 20A | - | 4.3 | 5.5 | mΩ | |
| Dynamic Characteristics | | | | | | | |
| Input Capacitance | Ciss | | - | 3543 | - | | |
| Output Capacitance | Coss | VDS =40V, VGS = 0V, f = 1.0MHz | - | 1058 | - | pF | |
| Reverse Transfer Capacitance | C _{rss} | | | 23 | - | 1 | |
| Total Gate Charge | Qg | VDS=40V , VGS=10V , ID=165A | - | 49 | - | nC | |
| Gate-Source Charge | Q _{gs} | | - | 16 | - | | |
| Gate-Drain Charge | Q_{gd} | 1 | | 13 | - | | |
| Switching Characteristics | | | | | | | |
| Turn-On Delay Time | t _{d(on)} | | - | 17 | - | | |
| Rise Time | t _r | VGS = 10V, VDS = 40V, ID=165A, | - | 25 | - | nS | |
| Turn-Off Delay Time | $t_{\text{d(off)}}$ | RG = 1.6Ω | - | 36 | - | 113 | |
| Fall Time | t _f | | - | 15 | - | | |
| Drain-Source Body Diode Characteristics | | | | | | | |
| Source-Drain Diode Forward Voltage | V_{SD} | $I_S = 1A$, $V_{GS} = 0V$ | - | - | 1.2 | V | |
| Maximum Body-Diode Continuous Current | Is | | - | - | 90 | Α | |
| Reverse Recovery Time | Trr | L=204 di/dt=1004/up TI=25°C | - | 62 | - | nS | |
| Reverse Recovery Charge | Qrr | l _S =20A, di/dt=100A/us, TJ=25℃ | | 103 | - | nC | |

Note:

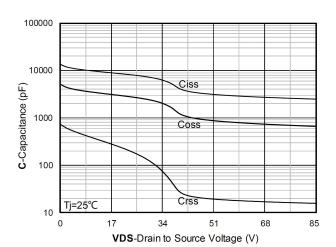
1. The test condition is VDD=45V,VGS=10V,L=0.5mH,RG=25 Ω

Typical Characteristics

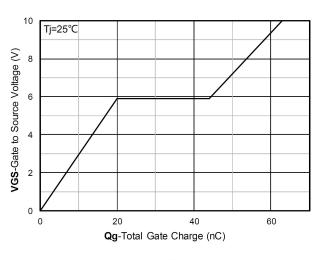




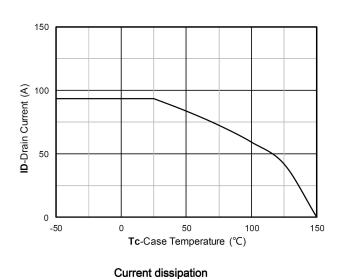




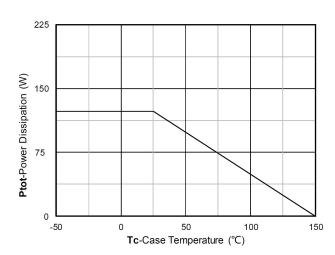
Transfer Characteristics



Capacitance Characteristics

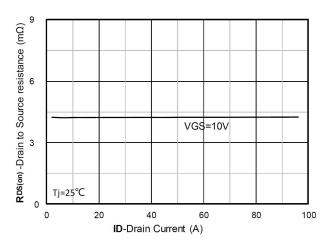


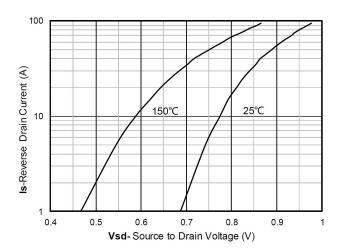
Gate Charge



Power dissipation

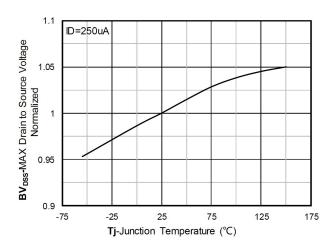


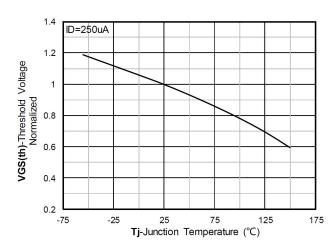




RDS(on) VS Drain Current

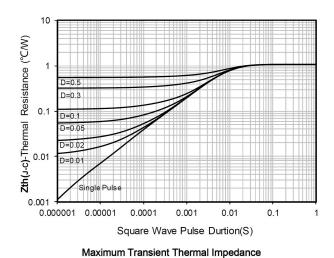
Forward characteristics of reverse diode

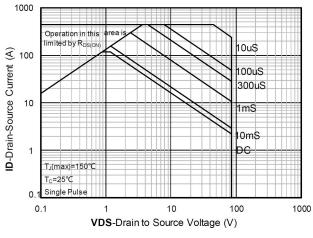




Normalized breakdown voltage

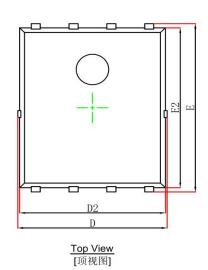
Normalized Threshold voltage

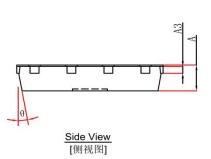


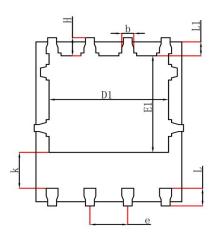


Safe Operation Area

PDFN5X6-8L Package Information







Bottom View [背视图]

| 0 | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-----------|----------------------|-------|--|
| Symbol | Min. | Max. | Min. | Max. | |
| А | 0.900 | 1.000 | 0.035 | 0.039 | |
| А3 | 0.254 | 0.254REF. | | REF. | |
| D | 4.944 | 5.096 | 0.195 | 0.201 | |
| E | 5.974 | 6.126 | 0.235 | 0.241 | |
| D1 | 3.910 | 4.110 | 0.154 | 0.162 | |
| E1 | 3.375 | 3.575 | 0.133 | 0.141 | |
| D2 | 4.824 | 4.976 | 0.190 | 0.196 | |
| E2 | 5.674 | 5.826 | 0.223 | 0.229 | |
| k | 1.190 | 1.390 | 0.047 | 0.055 | |
| b | 0.350 | 0.450 | 0.014 | 0.018 | |
| е | 1.270 | 1.270TYP. | | TYP. | |
| L | 0.559 | 0.711 | 0.022 | 0.028 | |
| L1 | 0.424 | 0.576 | 0.017 | 0.023 | |
| Н | 0.574 | 0.726 | 0.023 | 0.029 | |
| θ | 10° | 12° | 10° | 12° | |